# NSN 5961-01-117-5660

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## **Inclosure Material:**

Metal

**Overall Length:** 

0.210 inches

# **Overall Diameter:**

0.285 inches

## **End Application:**

An/apx-76b 80249 fscm

# **Mounting Facility Quantity:**

2

# Internal Configuration:

Junction contact

## **Mounting Method:**

Unthreaded hole

## Features Provided:

Hermetically sealed case

## Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

65.0 collector to base voltage/static/emitter open and 65.0 collector to emitter voltage, dc with base short-circuited to emitter and 3.5

emitter to base voltage, static, collector open

# **Power Rating Per Characteristic:**

75.0 watts small-signal input power, common-collector absolute

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

### **Special Features:**

Junction pattern arrangement: npn

## **Test Data Document:**

80249-911376 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

## Terminal Type And Quantity:

1 flange and 2 pin

Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

Fiig:

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